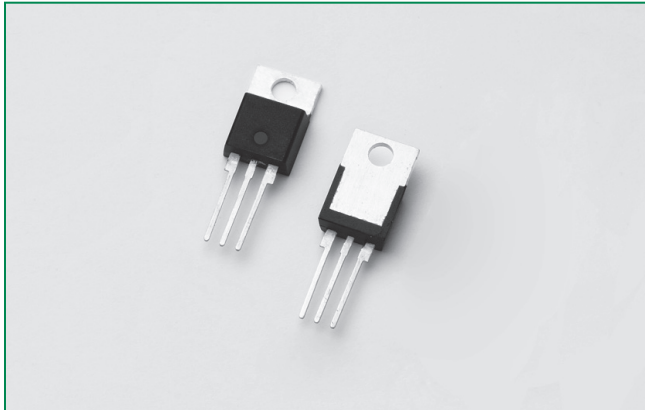


## SK625xD Series



### Description

Excellent unidirectional switches for phase control applications such as heating and motor speed controls.

Standard phase control SCRs are triggered with few milliamperes of current at less than 1.5V potential.

### Features & Benefits

- RoHS compliant
- Voltage capability up to 1600 V
- Surge capability up to 250 A
- Electrically isolated package "LD-Package" and UL recognized for 2500V<sub>RMS</sub>

### Agency Approval

| Agency | Agency File Number |
|--------|--------------------|
|        | E71639             |

### Main Features

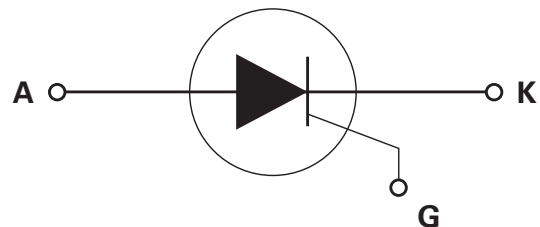
| Symbol            | Value | Unit |
|-------------------|-------|------|
| $I_{T(RMS)}$      | 25    | A    |
| $V_{DRM}/V_{RRM}$ | 1600  | V    |
| $I_{GT}$          | 35    | mA   |

### Applications

Typical applications are AC solid-state switches, industrial power tools, line rectification 50/60Hz.

Internally constructed isolated packages are offered for ease of heat sinking with highest isolation voltage.

### Schematic Symbol



**Absolute Maximum Ratings — 25A SCR**

| Symbol              | Parameter                                     | Test Conditions                                                                  |                          | Value      | Unit                   |
|---------------------|-----------------------------------------------|----------------------------------------------------------------------------------|--------------------------|------------|------------------------|
| $V_{DRM} / V_{RRM}$ | Repetitive Peak off-state/Reverse Voltage     |                                                                                  |                          | 1600       | V                      |
| $V_{DSM} / V_{RSM}$ | Non-repetitive peak off-state/Reverse voltage |                                                                                  |                          | 1700       | V                      |
| $I_{T(RMS)}$        | RMS on-state current                          | SK625LD                                                                          | $T_c = 60^\circ\text{C}$ | 25         | A                      |
|                     |                                               | SK625RD                                                                          | $T_c = 90^\circ\text{C}$ |            |                        |
| $I_{T(AV)}$         | Average on-state current                      | SK625LD                                                                          | $T_c = 60^\circ\text{C}$ | 16         | A                      |
|                     |                                               | SK625RD                                                                          | $T_c = 90^\circ\text{C}$ |            |                        |
| $I_{TSM}$           | Peak non-repetitive surge current             | single half cycle; $f = 50\text{Hz}$ ; $T_J (\text{initial}) = 25^\circ\text{C}$ |                          | 250        | A                      |
|                     |                                               | single half cycle; $f = 60\text{Hz}$ ; $T_J (\text{initial}) = 25^\circ\text{C}$ |                          | 300        |                        |
| $I^2t$              | $I^2t$ Value for fusing                       | $t_p = 8.3 \text{ ms}$                                                           |                          | 375        | $\text{A}^2\text{s}$   |
| $di/dt$             | Critical rate of rise of on-state current     |                                                                                  |                          | 100        | $\text{A}/\mu\text{s}$ |
| $I_{GM}$            | Peak gate current                             | $T_J = 125^\circ\text{C}$                                                        |                          | 1.5        | A                      |
| $P_{G(AV)}$         | Average gate power dissipation                | $T_J = 125^\circ\text{C}$                                                        |                          | 1          | W                      |
| $T_{stg}$           | Storage temperature range                     |                                                                                  |                          | -40 to 150 | $^\circ\text{C}$       |
| $T_J$               | Operating junction temperature range          |                                                                                  |                          | -40 to 125 | $^\circ\text{C}$       |

Notes :  
 x = package

**Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)**

| Symbol   | Test Conditions                                                                                                  |      | Value | Unit                   |
|----------|------------------------------------------------------------------------------------------------------------------|------|-------|------------------------|
| $I_{GT}$ | $V_D = 12\text{V}; R_L = 30\Omega$                                                                               | MAX. | 35    | mA                     |
| $V_{GT}$ |                                                                                                                  | MAX. | 1.5   | V                      |
| $dv/dt$  | $V_D = 2/3 V_{DRM}$ ; gate open; $T_J = 125^\circ\text{C}$                                                       | MIN. | 2000  | $\text{V}/\mu\text{s}$ |
| $V_{GD}$ | $V_D = V_{DRM}$ ; $R_L = 3.3 \text{ k}\Omega$ ; $T_J = 125^\circ\text{C}$                                        | MIN. | 0.2   | V                      |
| $I_H$    | $I_T = 500\text{mA}$ (initial)                                                                                   | MAX. | 120   | mA                     |
| $t_q$    | $I_T = 0.5\text{A}$ ; $t_p = 50\mu\text{s}$ ; $dv/dt = 5\text{V}/\mu\text{s}$ ; $di/dt = 30\text{A}/\mu\text{s}$ | TYP. | 25    | $\mu\text{s}$          |
| $t_{gt}$ | $I_G = 2 \times I_{GT}$ ; $PW = 15\mu\text{s}$ ; $I_T = 50\text{A}$                                              | TYP. | 5     | $\mu\text{s}$          |

Notes :  
 x = package

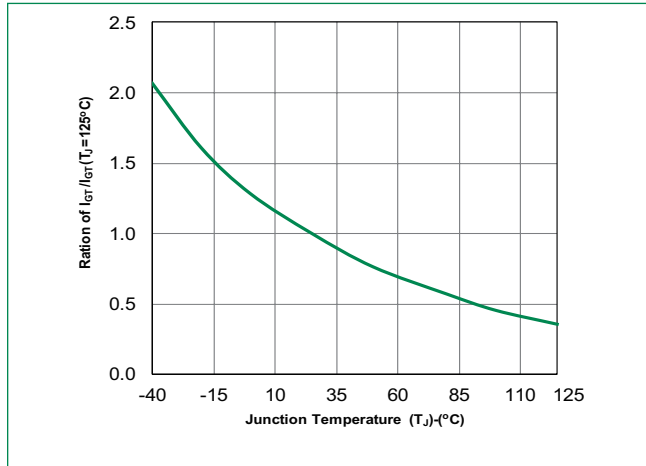
**Static Characteristics**

| Symbol              | Test Conditions                             |                           | Value | Unit          |
|---------------------|---------------------------------------------|---------------------------|-------|---------------|
| $V_{TM}$            | $I_T = 50\text{A}$ ; $t_p = 380\mu\text{s}$ | MAX.                      | 1.8   | V             |
| $I_{DRM} / I_{RRM}$ | $V_{DRM} / V_{RRM}$                         | $T_J = 25^\circ\text{C}$  | 10    | $\mu\text{A}$ |
|                     |                                             | $T_J = 125^\circ\text{C}$ | 4     | mA            |

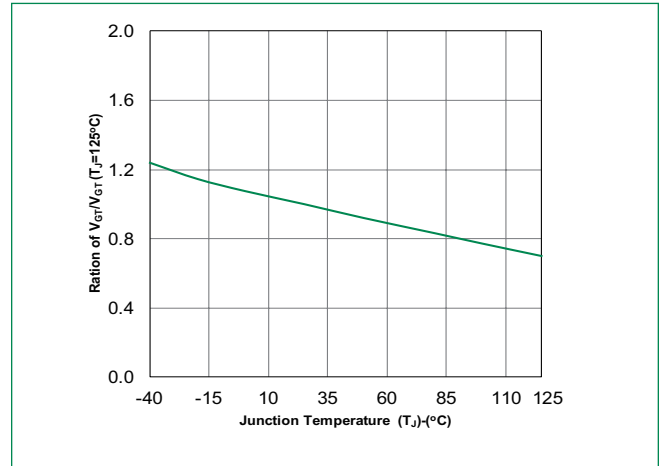
**Thermal Resistances**

| Symbol            | Parameter             | Value   | Unit |
|-------------------|-----------------------|---------|------|
| $R_{\theta(J-C)}$ | Junction to case (AC) | SK625RD | 1.0  |
|                   |                       | SK625LD | 1.9  |

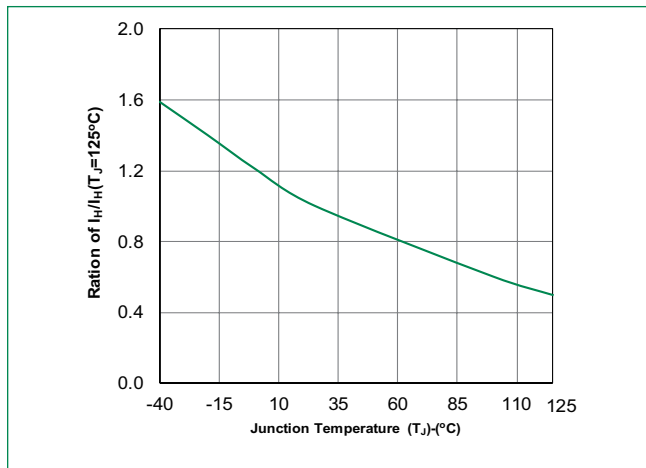
**Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature**



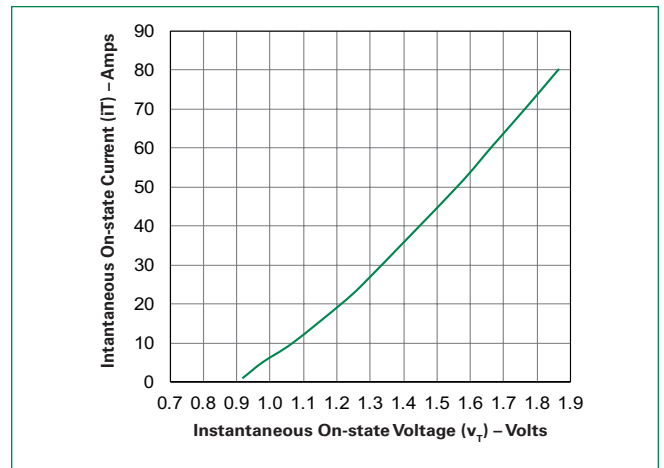
**Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature**



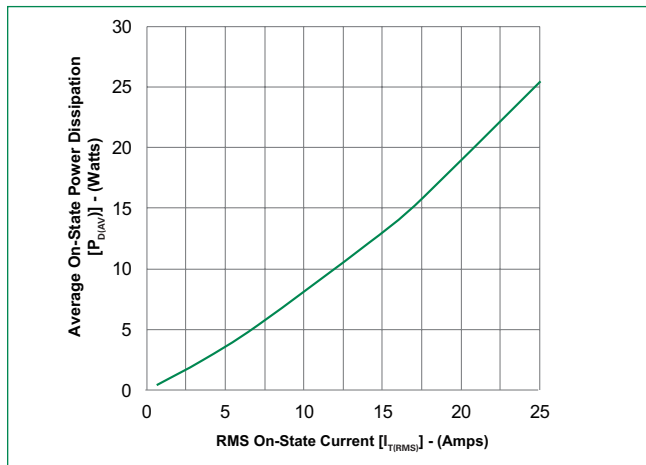
**Figure 3: Normalized DC Holding Current vs. Junction Temperature**



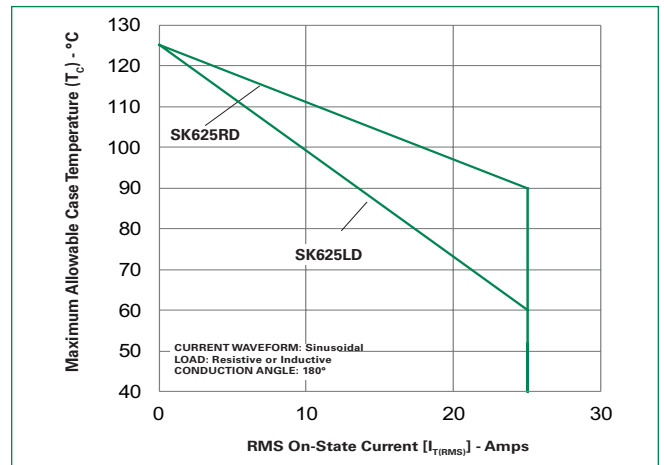
**Figure 4: On-State Current vs. On-State Voltage (Typical)**



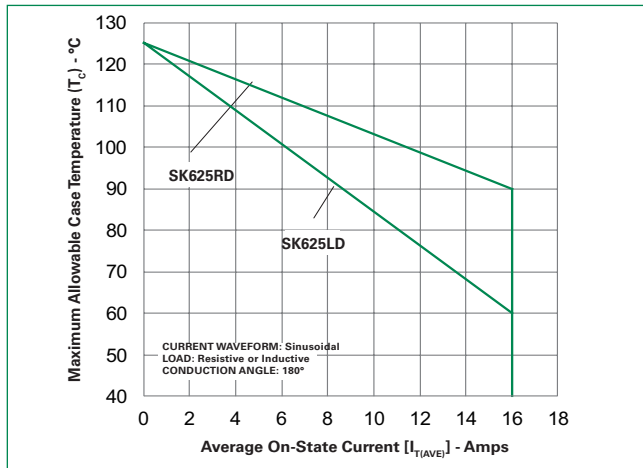
**Figure 5: Power Dissipation (Typical) vs. RMS On-State Current**



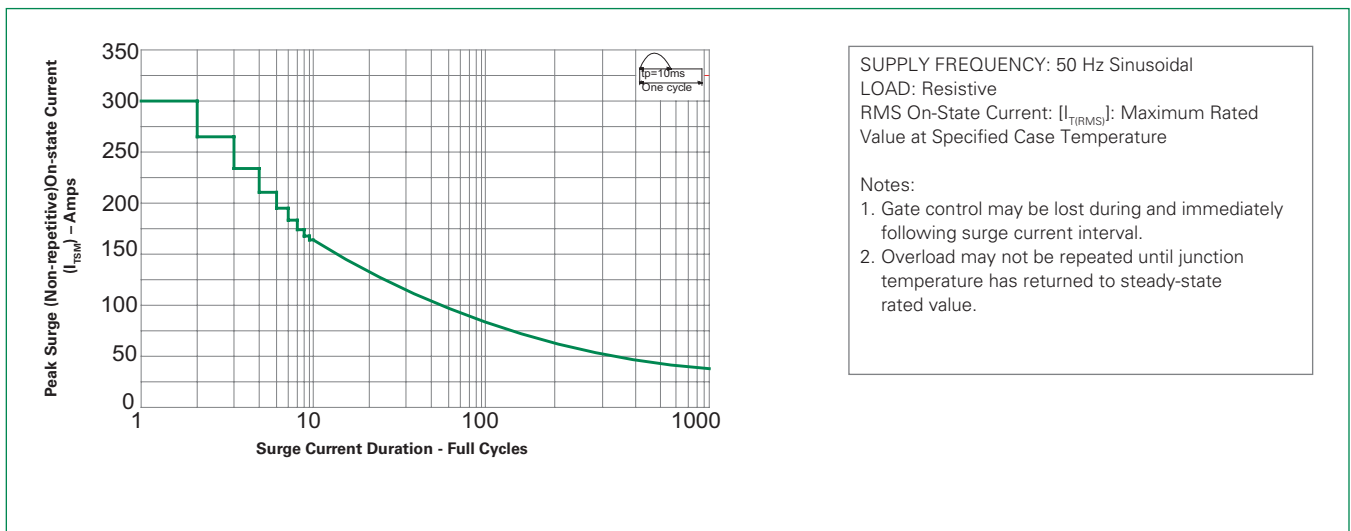
**Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current**



**Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current**



**Figure 8: Surge Peak On-State Current vs. Number of Cycles**



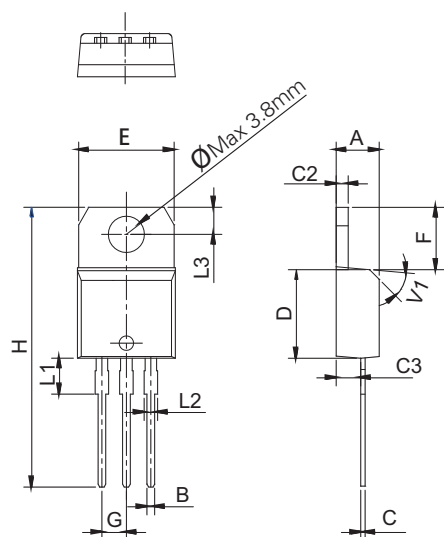
### Environmental Specifications

| Test                             | Specifications and Conditions                                         |
|----------------------------------|-----------------------------------------------------------------------|
| <b>AC Blocking</b>               | JESD22-A108C, 80% $V_{DRM}$ @125°C for 168 hours                      |
| <b>Temperature Cycling</b>       | MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time   |
| <b>Temperature/Humidity</b>      | EIA / JEDEC, JESD22-A101 168 hours; 100V - DC: 85°C; 85% rel humidity |
| <b>Resistance to Solder Heat</b> | JESD22-B106C                                                          |
| <b>Solderability</b>             | J-STD-022, category 3, test A                                         |

### Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including  $dv/dt$ ), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

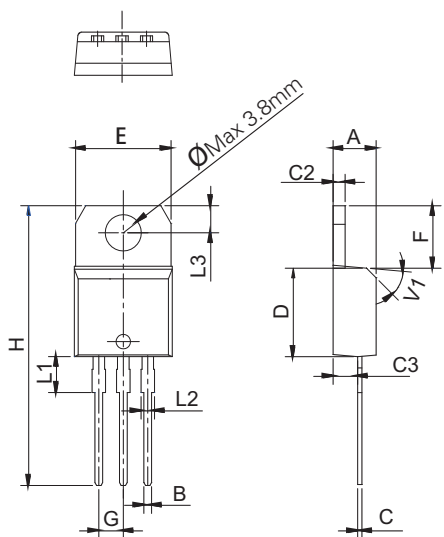
**Dimensions — TO-220AB (RD-Package) — Non-Isolated Mounting Tab Common with Center Lead**



Note: Maximum torque to be applied to mounting tab is 3 in-lbs (0.3Nm).

| Dimension | Millimeters |      |      | Inches |       |       |
|-----------|-------------|------|------|--------|-------|-------|
|           | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A         | 4.40        |      | 4.60 | 0.173  |       | 0.181 |
| B         | 0.61        |      | 0.88 | 0.024  |       | 0.035 |
| C         | 0.46        |      | 0.70 | 0.018  |       | 0.028 |
| C2        | 1.21        |      | 1.32 | 0.048  |       | 0.052 |
| C3        | 2.40        |      | 2.72 | 0.094  |       | 0.107 |
| D         | 8.60        |      | 9.70 | 0.339  |       | 0.382 |
| E         | 9.60        |      | 10.4 | 0.378  |       | 0.409 |
| F         | 6.20        |      | 6.60 | 0.244  |       | 0.260 |
| G         |             | 2.54 |      |        | 0.1   |       |
| H         | 28.0        |      | 29.8 | 1.102  |       | 1.173 |
| L1        |             | 3.75 |      |        | 0.148 |       |
| L2        | 1.14        |      | 1.70 | 0.045  |       | 0.067 |
| L3        | 2.65        |      | 2.95 | 0.104  |       | 0.116 |
| V1        |             | 45°  |      |        | 45°   |       |

**Dimensions — TO-220AB (LD-Package) — Isolated Mounting Tab**



Note: Maximum torque to be applied to mounting tab is 7 in-lbs. (0.8 Nm).

| Dimension | Millimeters |      |      | Inches |       |       |
|-----------|-------------|------|------|--------|-------|-------|
|           | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A         | 4.40        |      | 4.60 | 0.173  |       | 0.181 |
| B         | 0.61        |      | 0.88 | 0.024  |       | 0.035 |
| C         | 0.46        |      | 0.70 | 0.018  |       | 0.028 |
| C2        | 1.21        |      | 1.32 | 0.048  |       | 0.052 |
| C3        | 2.40        |      | 2.72 | 0.094  |       | 0.107 |
| D         | 8.60        |      | 9.70 | 0.339  |       | 0.382 |
| E         | 9.80        |      | 10.4 | 0.386  |       | 0.409 |
| F         | 6.55        |      | 6.95 | 0.258  |       | 0.274 |
| G         |             | 2.54 |      |        | 0.1   |       |
| H         | 28.0        |      | 29.8 | 1.102  |       | 1.173 |
| L1        |             | 3.75 |      |        | 0.148 |       |
| L2        | 1.14        |      | 1.70 | 0.045  |       | 0.067 |
| L3        | 2.65        |      | 2.95 | 0.104  |       | 0.116 |
| V1        |             | 45°  |      |        | 45°   |       |

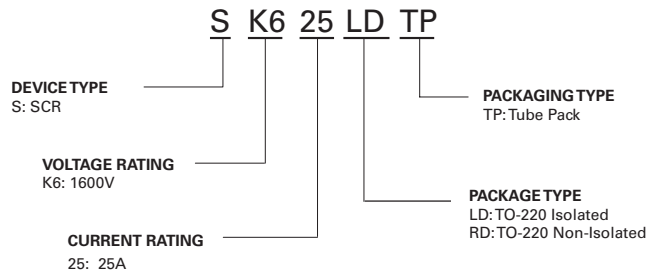
### Product Selector

| Part Number | Gate Sensitivity | Type         | Package |
|-------------|------------------|--------------|---------|
| SK625LD     | 35mA             | Standard SCR | TO-220L |
| SK625RD     | 35mA             | Standard SCR | TO-220R |

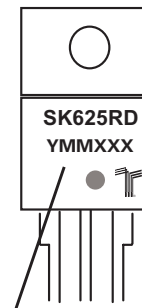
### Packing Options

| Part Number | Marking | Weight | Packing Mode | Base Quantity |
|-------------|---------|--------|--------------|---------------|
| SK625LDTP   | SK625LD | 2.2g   | Tube         | 1000          |
| SK625RDTP   | SK625RD | 2.0g   | Tube         | 1000          |

### Part Numbering System



### Part Marking System



**Date Code Marking**  
Y: Year Code  
MM: Month Code  
XXX: Lot Trace Code

## Данный компонент на территории Российской Федерации

**Вы можете приобрести в компании MosChip.**

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9